



## Product Summary

BV <sub>DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
30V	11mΩ @ V <sub>GS</sub> = 10V	10.5A
	15mΩ @ V <sub>GS</sub> = 4.5V	9.2A

## Features and Benefits

- Low R<sub>DS(on)</sub> – Ensures On-State Losses Are Minimized
- 100% Unclamped Inductive Switching, Test in Production – Ensures More Reliable And Robust End Application
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of The Board Area Occupied by SO-8 Enabling Smaller End Product
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **The DMG7430LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**  
<https://www.diodes.com/quality/product-definitions/>

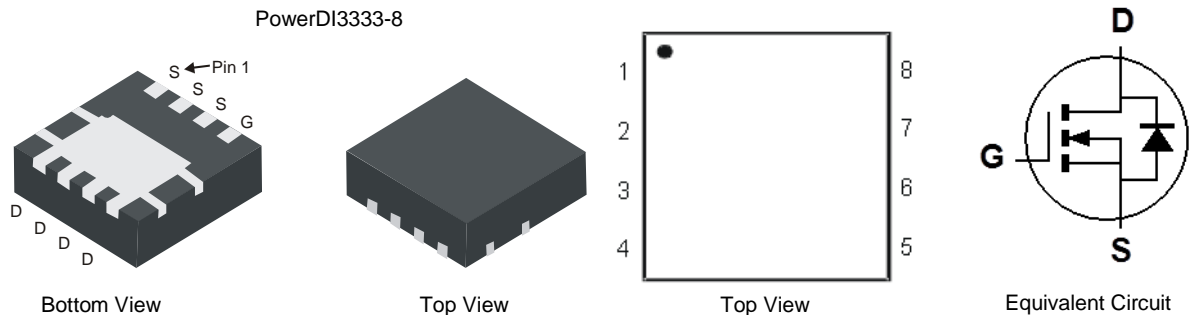
## Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Power-management functions
- DC-DC converters

## Mechanical Data

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.034 grams (Approximate)

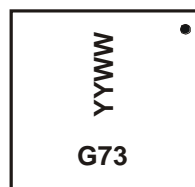


## Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
DMG7430LFGQ-7	PowerDI3333-8	2000	Tape & Reel
DMG7430LFGQ-13	PowerDI3333-8	3000	Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



G73 = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 23 = 2023)  
 WW = Week Code (01 to 53)

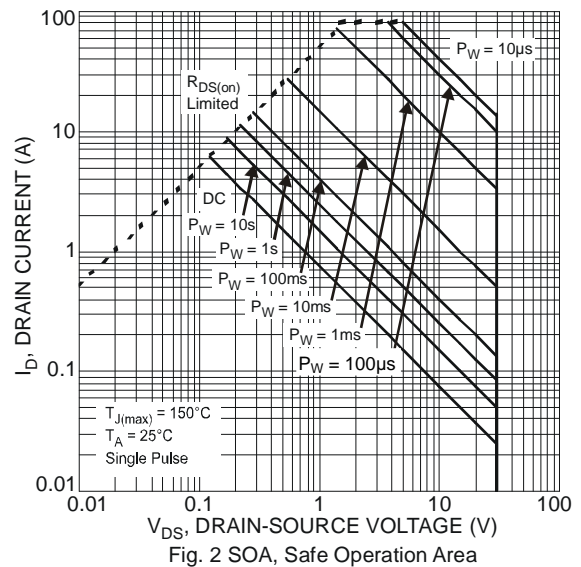
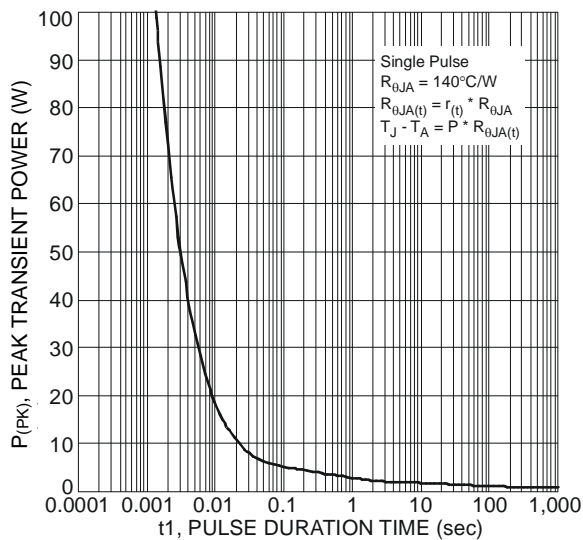
**Maximum Ratings** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		$V_{DSS}$	30	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Continuous Drain Current (Note 6) $V_{GS} = 10\text{V}$	Steady State	$I_D$	10.5 8.5	A
	$t < 10\text{s}$	$I_D$	14 11	A
Pulsed Drain Current (10 $\mu\text{s}$ Pulse, Duty Cycle = 1%)		$I_{DM}$	90	A
Maximum Continuous Body Diode Forward Current (Note 6)		$I_S$	3.0	A
Avalanche Current (Note 7) $L = 0.1\text{mH}$		$I_{AR}$	22	A
Repetitive Avalanche Energy (Note 7) $L = 0.1\text{mH}$		$E_{AR}$	24	mJ

**Thermal Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	Steady State	$P_D$	0.9	W
	$t < 10\text{s}$		1.5	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	142	$^\circ\text{C/W}$
	$t < 10\text{s}$		78	
Total Power Dissipation (Note 6)	Steady State	$P_D$	2.2	W
	$t < 10\text{s}$		3.5	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	59	$^\circ\text{C/W}$
	$t < 10\text{s}$		33	
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	11	
Operating and Storage Temperature Range		$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
  - Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
  - $I_{AR}$  and  $E_{AR}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^\circ\text{C}$ .



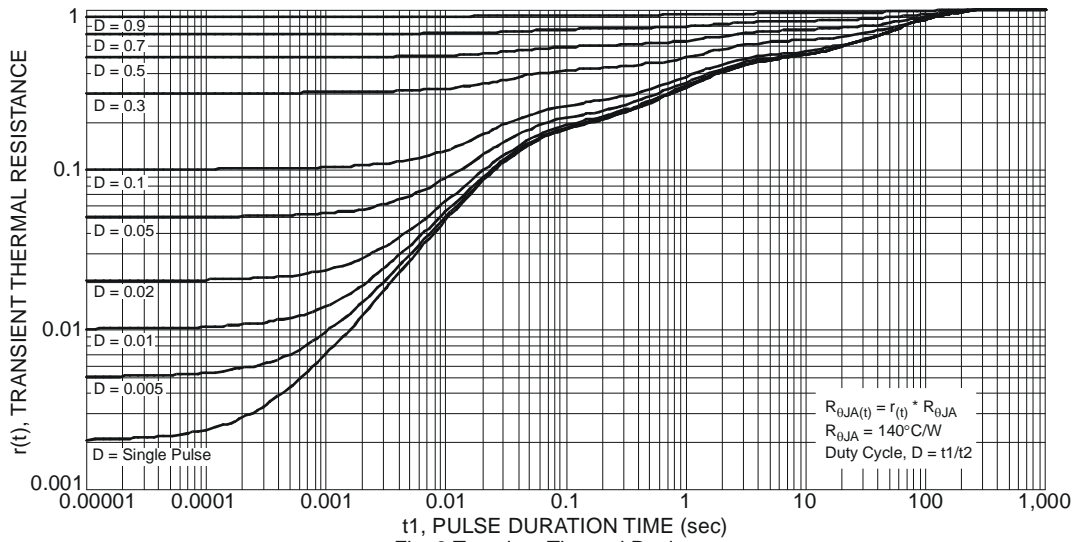


Fig. 3 Transient Thermal Resistance

**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	30	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	1	$\mu A$	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	$V_{GS(th)}$	1.4	—	2.5	V	$V_{DS} = V_{GS}, I_D = 250\mu A$
Static Drain-Source On-Resistance	$R_{DS(on)}$	—	7	11	m $\Omega$	$V_{GS} = 10V, I_D = 20A$
		—	11	15		$V_{GS} = 4.5V, I_D = 20A$
Forward Transfer Admittance	$ Y_{fs} $	—	74	—	S	$V_{DS} = 5V, I_D = 20A$
Diode Forward Voltage	$V_{SD}$	—	0.75	1.0	V	$V_{GS} = 0V, I_S = 1A$
<b>DYNAMIC CHARACTERISTICS (Note 9)</b>						
Input Capacitance	$C_{iss}$	—	1281	—	pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz$
Output Capacitance	$C_{oss}$	—	145	—	pF	
Reverse Transfer Capacitance	$C_{rss}$	—	125	—	pF	
Gate Resistance	$R_g$	—	1.2	—	$\Omega$	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge ( $V_{GS} = 4.5V$ )	$Q_g$	—	12.5	—	nC	$V_{DS} = 15V, I_D = 12A$
Total Gate Charge ( $V_{GS} = 10V$ )	$Q_g$	—	26.7	—	nC	
Gate-Source Charge	$Q_{gs}$	—	3.6	—	nC	
Gate-Drain Charge	$Q_{gd}$	—	4.4	—	nC	
Turn-On Delay Time	$t_{D(on)}$	—	5.2	—	ns	$V_{DD} = 15V, V_{GS} = 10V, R_L = 1.25\Omega, R_G = 3\Omega$
Turn-On Rise Time	$t_R$	—	21.2	—	ns	
Turn-Off Delay Time	$t_{D(off)}$	—	22.3	—	ns	
Turn-Off Fall Time	$t_F$	—	5.1	—	ns	
Reverse Recovery Time	$t_{RR}$	—	8.5	—	ns	$I_F = 12A, di/dt = 500A/\mu s$
Reverse Recovery Charge	$Q_{RR}$	—	7.0	—	nC	$I_F = 12A, di/dt = 500A/\mu s$

Notes: 8. Short duration pulse test used to minimize self-heating effect.  
9. Guaranteed by design. Not subject to product testing.

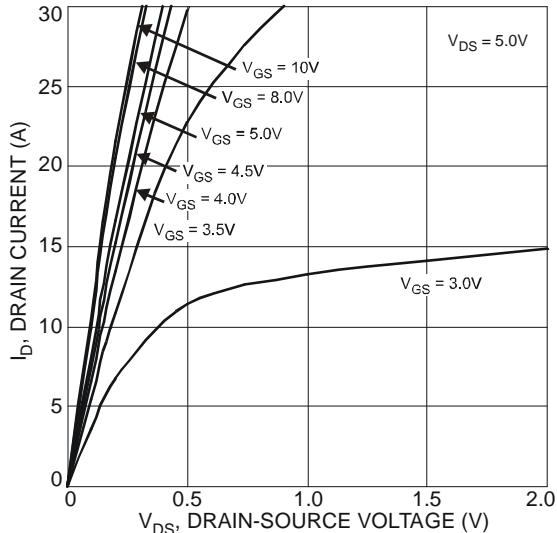


Fig. 4 Typical Output Characteristic

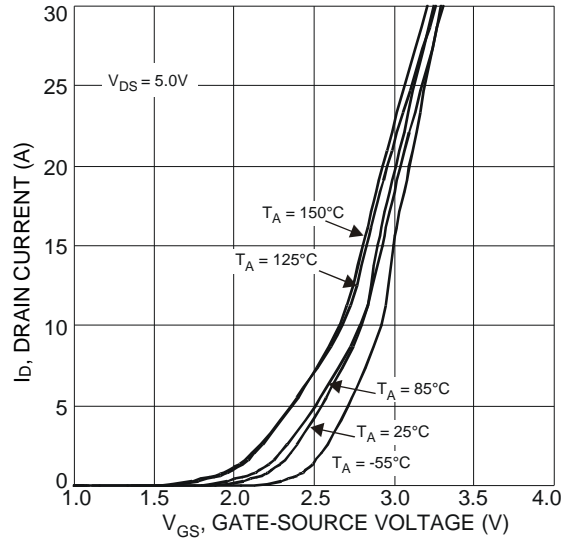


Fig. 5 Typical Transfer Characteristics

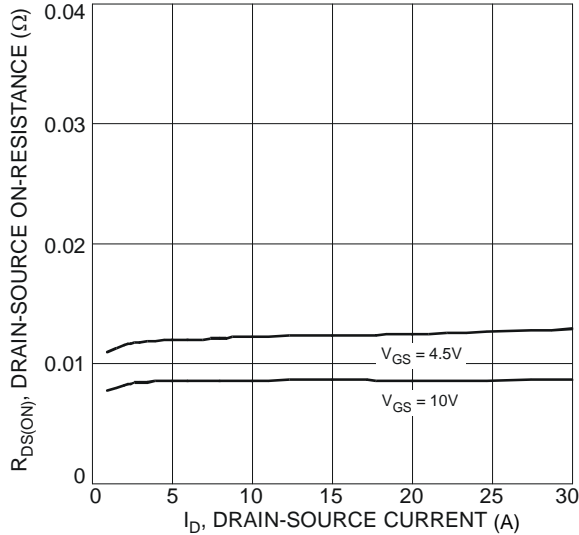


Fig. 6 Typical On-Resistance vs. Drain Current and Gate Voltage

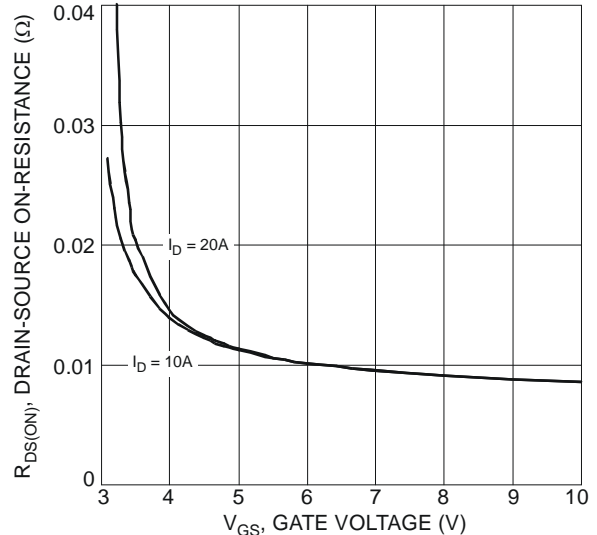


Fig. 7 Typical On-Resistance vs. Gate Voltage

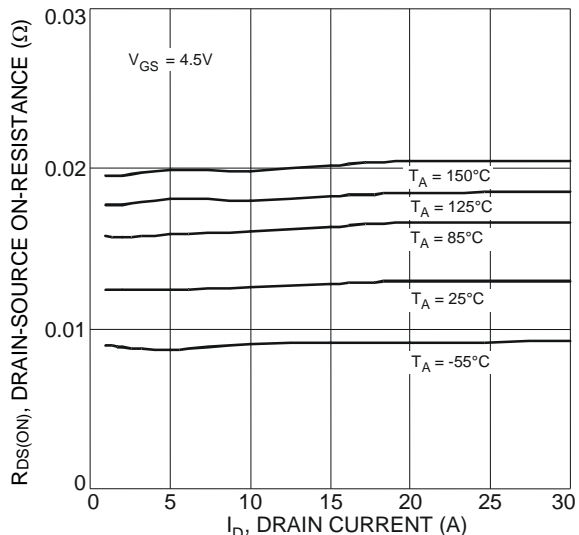


Fig. 8 Typical On-Resistance vs. Drain Current and Temperature

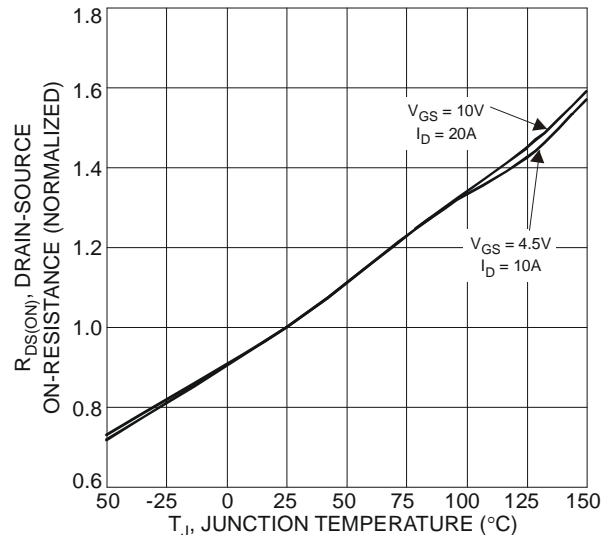


Fig. 9 On-Resistance Variation with Temperature

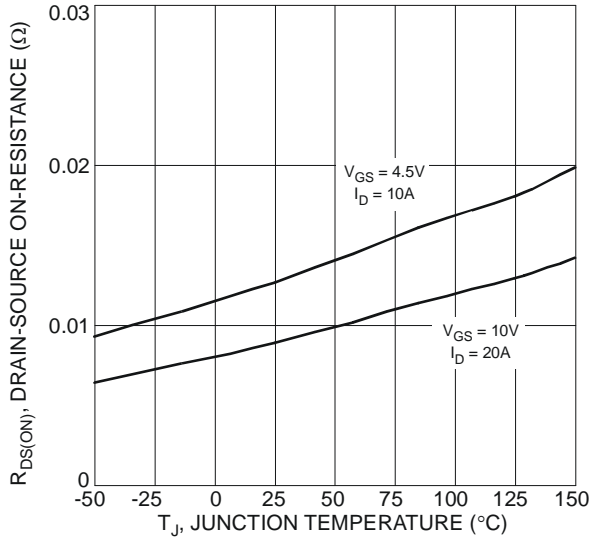


Fig. 10 On-Resistance Variation with Temperature

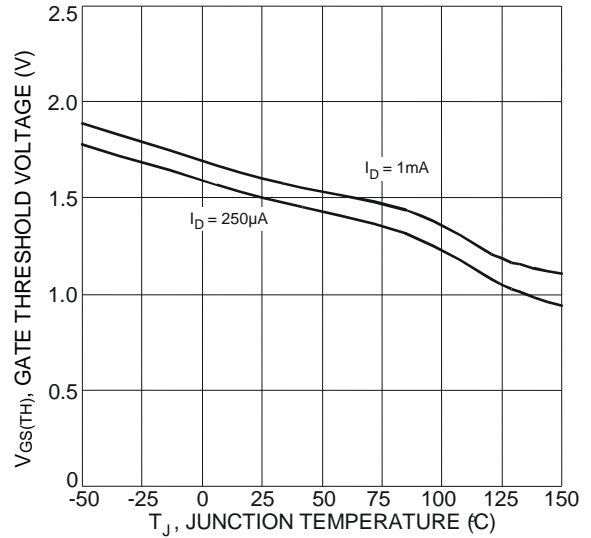


Fig. 11 Gate Threshold Variation vs. Junction Temperature

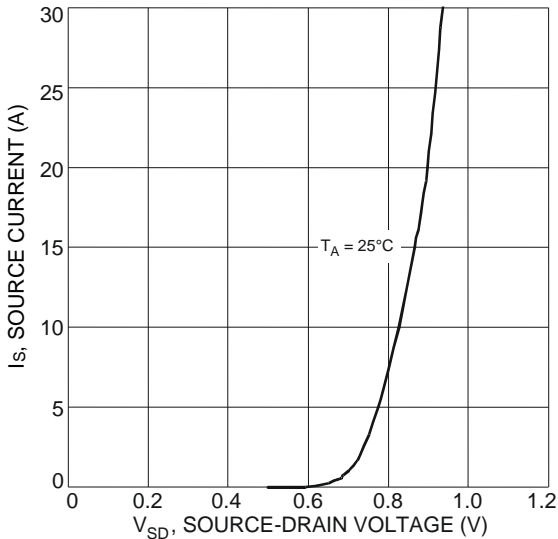


Fig.12 Diode Forward Voltage vs. Current

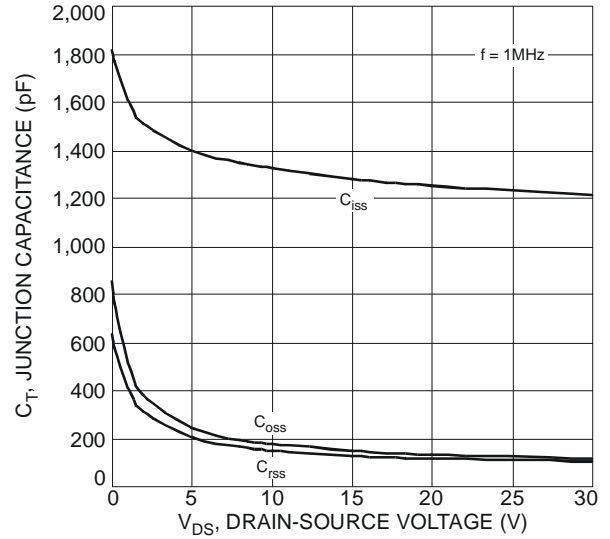


Fig. 13 Typical Junction Capacitance

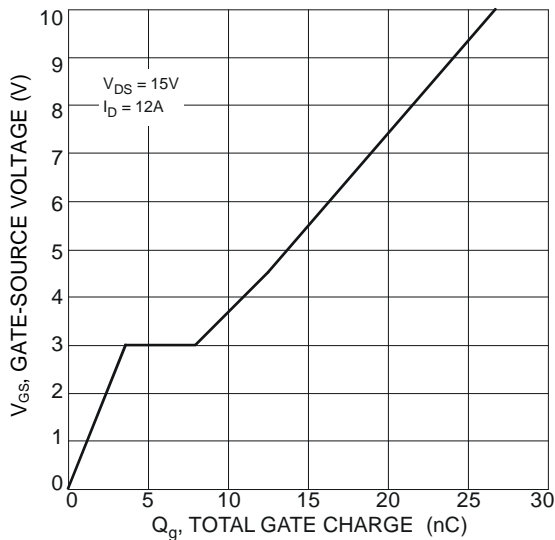


Fig. 14 Gate Charge



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